

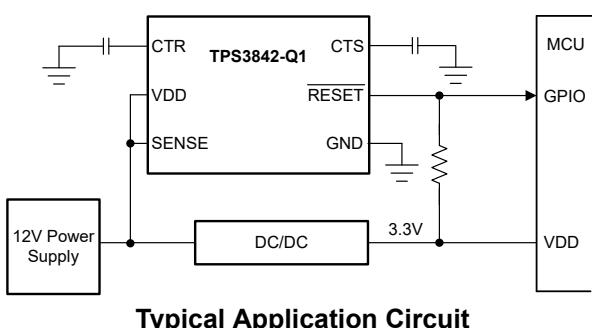
# TPS3842-Q1 Automotive 42V Small Size, 850nA Undervoltage or Overvoltage Supervisor With Programmable Delay and De-Glitch

## 1 Features

- AEC-Q100 qualified with the following results:
  - Device temperature grade 1:  $-40^{\circ}\text{C}$  to  $+125^{\circ}\text{C}$  ambient operating temperature  $T_A$
  - Device HBM ESD classification level 2
  - Device CDM ESD classification level C7B
- Wide supply voltage range: 1.9V to 42V
- VDD, SENSE, and  $\overline{\text{RESET}}$  are rated to 42V
- Very low quiescent current: 850nA (typical)
- High threshold accuracy: 0.5% (typical)
- Fixed internal threshold voltages: 2.7V to 9.5V
- Adjustable voltage variant: 0.7V
- Capacitor adjustable delay time with CTR pin
- Capacitor adjustable de-glitch time with CTS pin
- Undervoltage open-drain, active-low output
- Overvoltage open-drain, active-low and active-high output
- Temperature range:  $-40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$
- Small size: SOT5X3 (DRL)

## 2 Applications

- ADAS domain controller
- Automotive gateway
- Automotive head unit
- Digital cockpit processing unit
- Telematics control unit
- Driver monitoring



Typical Application Circuit

## 3 Description

The TPS3842-Q1 is an automotive 42V input voltage supervisor with 850nA  $I_{DD}$  and 1.5% accuracy, and a fast detection time. The TPS3842-Q1 can be connected directly to 12V battery for continuous monitoring of undervoltage (UV) conditions or overvoltage (OV) conditions. The TPS3842-Q1 comes in a small DRL package for size constrained applications. Built-in hysteresis on the SENSE pin prevents false reset signals when monitoring a supply voltage rail. 1%, 5%, and 10% hysteresis voltage options are available to offer design flexibility to support voltage transients.

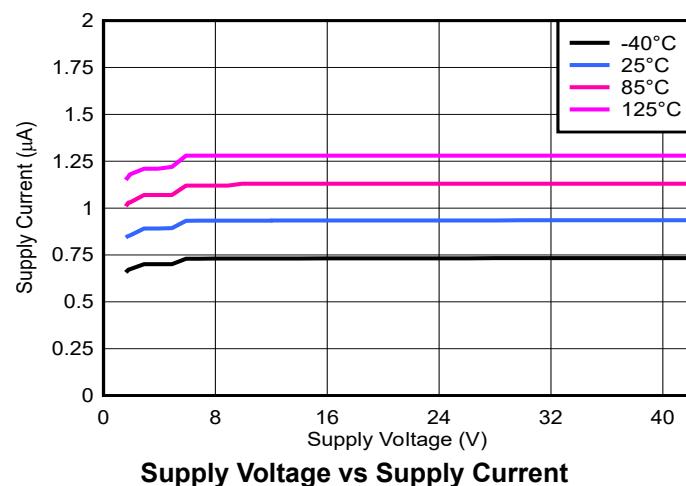
SENSE is decoupled from VDD and can monitor higher and lower voltages than VDD. Fixed threshold variants provide accurate low-I<sub>q</sub> voltage monitoring. Adjustable threshold variants offer flexible undervoltage threshold setting with external resistors. TPS3842-Q1 offers capacitor programmable de-glitch on the SENSE with the CTS pin and capacitor programmable reset delay timing with the CTR pin.

### Device Information

PART NUMBER	PACKAGE <sup>(1)</sup>	BODY SIZE (NOM) <sup>(2)</sup>
TPS3842-Q1	SOT5X3 (6)	1.20mm x 1.60mm

(1) For all available packages, see the orderable addendum at the end of the data sheet.

(2) The package size (length  $\times$  width) is a nominal value and includes pins, where applicable.



Supply Voltage vs Supply Current



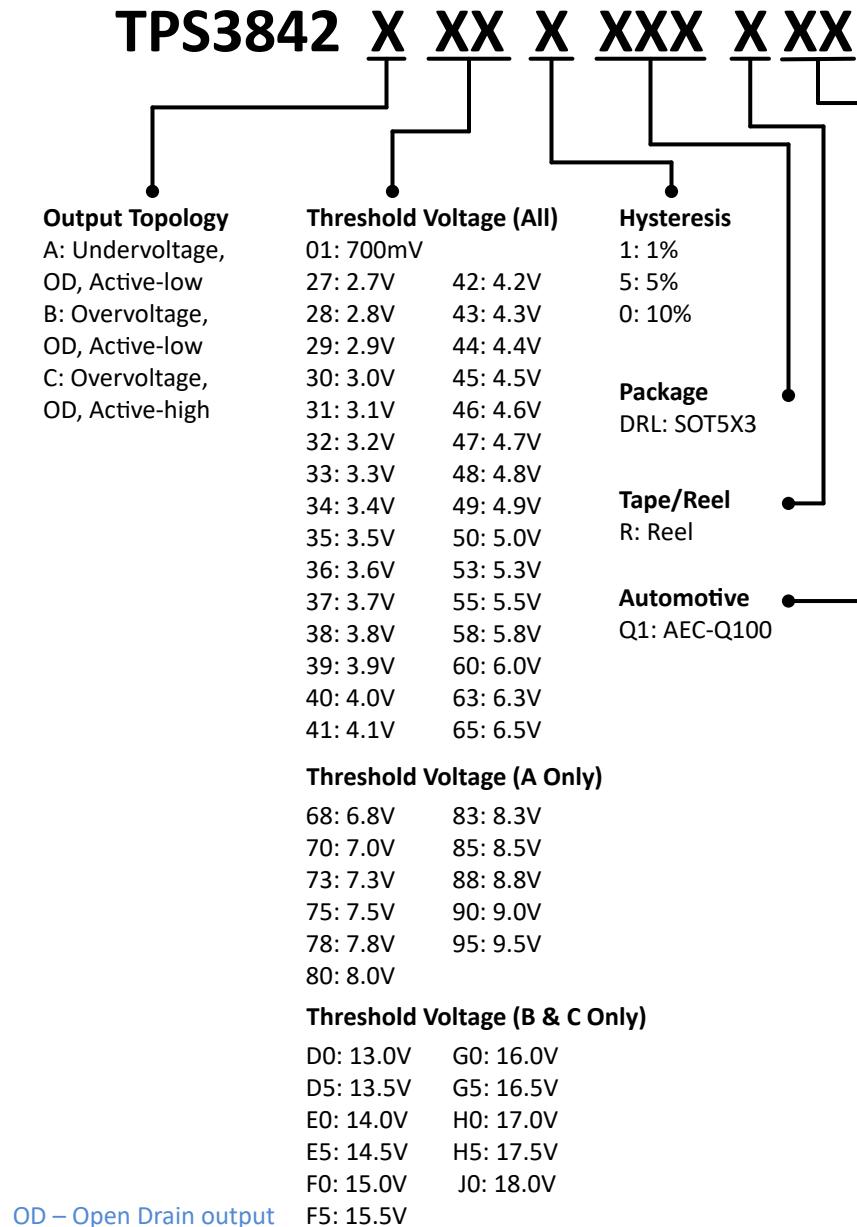
An IMPORTANT NOTICE at the end of this data sheet addresses availability, warranty, changes, use in safety-critical applications, intellectual property matters and other important disclaimers. PRODUCTION DATA.

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## 4 Device Comparison

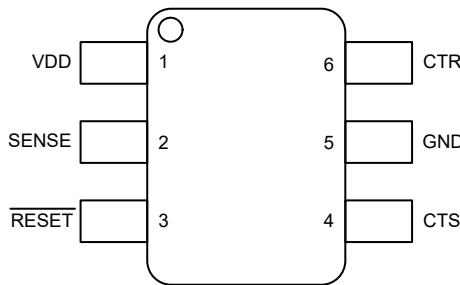
[Device Naming Convention](#) shows some of the device naming nomenclature of the TPS3842-Q1. Contact TI sales representatives or on [TI's E2E forum](#) for detail and availability of other options.



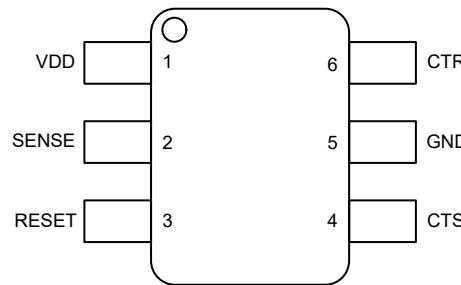
**Figure 4-1. Device Naming Convention**

1. Suffix 01 with  $V_{ITN}$  of 700mV corresponds to the adjustable variant, does not have internal voltage divider resistor ladder.

## 5 Pin Configuration and Functions



**Figure 5-1. TPS3842A, TPS3842B DRL Package  
6-Pin SOT5X3  
Top View**



**Figure 5-2. TPS3842C DRL Package  
6-Pin SOT5X3  
Top View**

**Table 5-1. Pin Functions**

PIN		I/O	DESCRIPTION
NAME	SOT5X3		
VDD	1	I	Supply voltage pin.
SENSE	2	I	Sense input. Monitors input voltage based on internal voltage threshold. See <a href="#">Section 7.3.1</a> for more details.
RESET	3	O	Output reset signal for active-low variants. Connect RESET to pull up voltage using a pull up resistance. See <a href="#">Section 7.3.4</a> for more details.
RESET	3	O	Output reset signal for active-high variants. Connect RESET to pull up voltage using a pull up resistance. See <a href="#">Section 7.3.4</a> for more details.
CTS	4	I	Sense time delay: Capacitor programmable sense delay: CTS pin offers a user adjustable sense delay time when asserting a reset condition. See <a href="#">Section 7.3.2</a> for more details.
GND	5	—	Ground pin.
CTR	6	I	Reset time delay: User-programmable reset time delay for RESET pin. Connect an external capacitor for adjustable time delay or leave the pin floating for the shortest delay. See <a href="#">Section 7.3.3</a> for more details.

## 6 Specification

### 6.1 Absolute Maximum Ratings

over operating free-air temperature range (unless otherwise noted)<sup>(1)</sup>

		MIN	MAX	UNIT
Voltage	$V_{DD}$ , $V_{SENSE}$ , $V_{RESET}$ , $V_{RESET}$	-0.3	50	V
Voltage	$V_{CTR}$ , $V_{CTS}$	-0.3	5.5	V
Current	$I_{RESET}$ , $I_{RESET}$		$\pm 40$	mA
Temperature <sup>(2)</sup>	Operating junction temperature, $T_J$	-55	150	°C
	Operating free-air temperature, $T_A$	-55	150	°C
	Storage temperature, $T_{stg}$	-65	150	°C

(1) Stresses beyond values listed under Absolute Maximum Ratings can cause permanent damage to the device. These are stress ratings only, which do not imply functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions. Exposure to absolute-maximum-rated conditions for extended periods can affect device reliability.

(2) As a result of the low dissipated power in this device, the operating temperature is assumed that  $T_J = T_A$ .

### 6.2 ESD Ratings

		VALUE	UNIT
$V_{(ESD)}$	Human body model (HBM), per AEC Q100-002 <sup>(1)</sup>	$\pm 2000$	V
	Charged device model (CDM), per AEC Q100-011	$\pm 750$	

(1) AEC Q100-002 indicates that HBM stressing shall be in accordance with the ANSI/ESDA/JEDEC JS-001 specification.

### 6.3 Recommended Operating Conditions

		MIN	NOM	MAX	UNIT
Voltage	$V_{DD}$	1.9	42	V	
Voltage	$V_{SENSE}$ , $V_{RESET}$ , $V_{RESET}$	0	42	V	
Voltage	$V_{CTS}$ , $V_{CTR}$	0	5	V	
Current	$I_{RESET}$ , $I_{RESET}$	0	10	mA	
$T_A$	Junction temperature (free-air temperature)	-40	125	°C	

### 6.4 Thermal Information

THERMAL METRIC <sup>(1)</sup>		TPS3842-Q1	UNIT
		DRL	
		6 PINS	
$R_{\theta JA}$	Junction-to-ambient thermal resistance	153.4	°C/W
$R_{\theta JC(\text{top})}$	Junction-to-case (top) thermal resistance	86.3	°C/W
$R_{\theta JB}$	Junction-to-board thermal resistance	42.8	°C/W
$\Psi_{JT}$	Junction-to-top characterization parameter	2.9	°C/W
$\Psi_{JB}$	Junction-to-board characterization parameter	41.2	°C/W

(1) For more information about traditional and new thermal metrics, see the [Semiconductor and IC Package Thermal Metrics application report](#).

## 6.5 Electrical Characteristics

At  $1.9V \leq V_{DD} \leq 42V$ ,  $CTS = CTR = \text{Open}$ ,  $\overline{\text{RESET}}$  Voltage ( $V_{\overline{\text{RESET}}}$ ) =  $100\text{k}\Omega$  to  $V_{DD}$ ,  $\overline{\text{RESET}}$  load =  $50\text{pF}$ , and over the operating free-air temperature range of  $-40^{\circ}\text{C}$  to  $125^{\circ}\text{C}$ , unless otherwise noted. Typical values are at  $T_A = 25^{\circ}\text{C}$ .

PARAMETER		TEST CONDITIONS	MIN	TYP	MAX	UNIT
$V_{DD}$	Supply Voltage		1.9	42		V
$V_{POR}$	Power on reset voltage <sup>(1)</sup> (Undervoltage variants)	$V_{OL}(\text{max}) = 0.25V$ , $I_{\overline{\text{RESET}}(\text{Sink})} = 15\mu\text{A}$			1.3	V
	Power on reset voltage <sup>(1)</sup> (Overvoltage variants)	$V_{OL}(\text{max}) = 0.25V$ , $I_{\overline{\text{RESET}}(\text{Sink})} = 15\mu\text{A}$ or $I_{\overline{\text{RESET}}(\text{Sink})} = 15\mu\text{A}$			1.7	V
$V_{ITN}$	Negative-going threshold accuracy (Undervoltage variants)	Fixed internal threshold, $V_{ITN} = 2.7V$ to $9.5V$	-1.5	$\pm 0.5$	1.5	%
		Adjustable internal threshold, $V_{ITP} = 700\text{mV}$	-1.5	$\pm 0.5$	1.5	%
$V_{ITP}$	Positive-going threshold accuracy (Overvoltage variants)	Fixed internal threshold, $V_{ITP} = 2.7V$ to $6.5V$ , $13V$ to $18V$	-1.5	$\pm 0.5$	1.5	%
		Adjustable internal threshold, $V_{ITP} = 700\text{mV}$	-1.5	$\pm 0.5$	1.5	%
$V_{HYS}$	Hysteresis Voltage <sup>(2)</sup>	1% Variant	0.5	1	1.5	%
$V_{HYS}$	Hysteresis Voltage <sup>(2)</sup>	5% Variant	4.5	5	5.5	%
$V_{HYS}$	Hysteresis Voltage <sup>(2)</sup>	10% Variant	9.5	10	10.5	%
$I_{DD}$	Supply current	$V_{DD} = 12V$ , $\overline{\text{RESET}}$ or $\overline{\text{RESET}}$ = Not asserted		0.85	1.9	$\mu\text{A}$
$I_{SENSE}$	Input current, SENSE pin	$V_{SENSE} = V_{IT}$ , Adjustable version			25	nA
$I_{SENSE}$	Input current, SENSE pin	$V_{SENSE} = 12V$ , Fixed versions		1.35	2.5	$\mu\text{A}$
$V_{OL}$	Low level output voltage	$1.9V \leq V_{DD} < 42V$ , $I_{\overline{\text{RESET}}(\text{Sink})} = 0.5\text{mA}$ or $I_{\overline{\text{RESET}}(\text{Sink})} = 0.5\text{mA}$			300	mV
$I_{LKG}$	Open drain output leakage current	$V_{DD} = V_{\overline{\text{RESET}}} = V_{\overline{\text{RESET}}} = 12V$			300	nA

(1)  $V_{POR}$  is the minimum  $V_{DD}$  voltage level for a controlled output state.

(2) Hysteresis is with respect of the trip point  $V_{ITP}$ .

## 6.6 Timing Requirements

At  $1.9V \leq V_{DD} \leq 42V$ ,  $CTS = CTR = Open$ ,  $\overline{RESET}$  Voltage ( $V_{RESET}$ ) =  $100k\Omega$  to  $V_{DD}$ ,  $\overline{RESET}$  load =  $50pF$ , and over the operating free-air temperature range of  $-40^{\circ}C$  to  $125^{\circ}C$ , unless otherwise noted. Typical values are at  $T_A = 25^{\circ}C$ .

			MIN	NOM	MAX	UNIT
$t_{GI(VIT)}$	Glitch Immunity undervoltage $V_{ITN(UV)}$ , 20% Overdrive <sup>(1)</sup>	$CTS = Open$		5		$\mu s$
	Glitch Immunity overvoltage $V_{ITP(OV)}$ , 20% Overdrive <sup>(1)</sup>	$CTS = Open$		5		$\mu s$

(1) 20% Overdrive from threshold. Overdrive % =  $[V_{SENSE} + V_{ITP}] / V_{ITP}$

## 6.7 Switching Characteristics

At  $1.9V \leq V_{DD} \leq 42V$ ,  $CTS = CTR = Open$ ,  $\overline{RESET}$  Voltage ( $V_{RESET}$ ) =  $100k\Omega$  to  $V_{DD}$ ,  $\overline{RESET}$  load =  $50pF$ , and over the operating free-air temperature range of  $-40^{\circ}C$  to  $125^{\circ}C$ , unless otherwise noted. Typical values are at  $T_A = 25^{\circ}C$ .

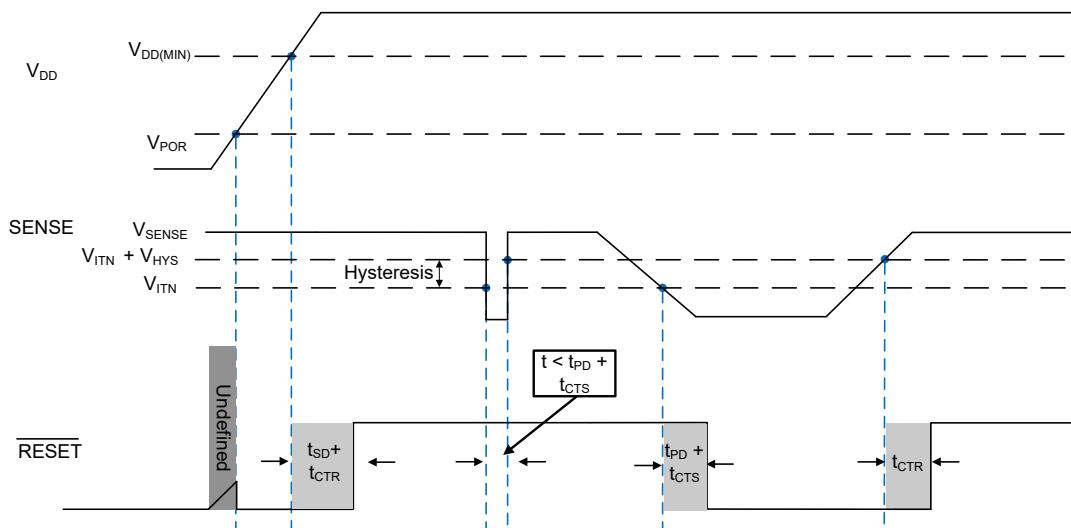
			MIN	NOM	MAX	UNIT
$t_{CTR}$	Reset time delay	$CTR = Open$		250		$\mu s$
$t_{CTR}$	Reset time delay	$CTR = 0.1\mu F$		285.8		ms
$t_{CTR}$	Reset time delay	$CTR = 3.3\mu F$		9.43		s
$t_{PD}$	Propagation detect delay <sup>(1) (2)</sup>	$CTS = Open, ADJ V_{th}$		7		$\mu s$
$t_{PD}$	Propagation detect delay <sup>(1) (2)</sup>	$CTS = Open, Fixed V_{th}$		9		$\mu s$
$t_{CTS}$	Sense time delay	$CTS = 0.1\mu F$		300		ms
$t_{SD}$	Startup delay <sup>(3)</sup>			300		$\mu s$

(1) 20% Overdrive from threshold. Overdrive % =  $[V_{SENSE} + V_{ITP}] / V_{ITP}$

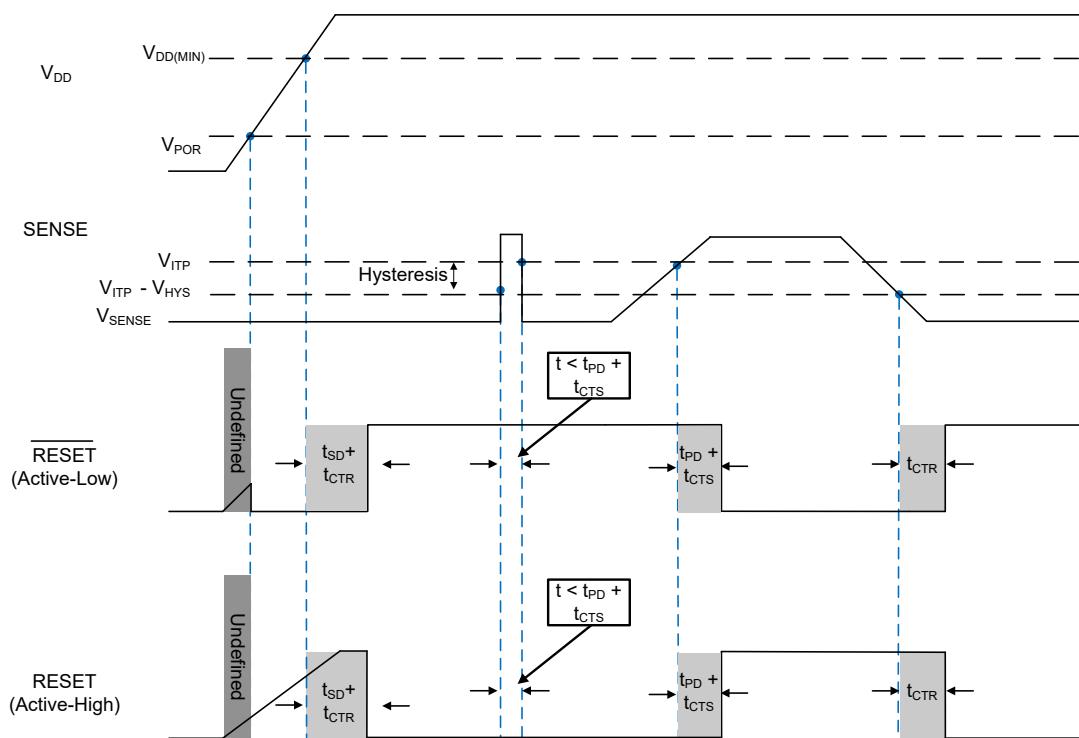
(2)  $t_{PD}$  measured from threshold trip point ( $V_{ITP}$ ) to  $\overline{RESET} V_{OL}$  voltage for active-low devices and to  $\overline{RESET} V_{OH}$  for active-high devices

(3) During the power-on sequence,  $V_{DD}$  must be at or above  $V_{DD(\text{MIN})}$  for at least  $t_{SD} + t_{CTR}$  before the output is in the correct state.

## 6.8 Timing Diagram



**Figure 6-1. Undervoltage Timing Diagram**



**Figure 6-2. Overvoltage Timing Diagram**

## 6.9 Typical Characteristics

At  $T_A = 25^\circ\text{C}$ ,  $V_{DD} = 3.3\text{V}$ ,  $R_{RESET} = 100\text{k}\Omega$ , and  $C_{LRESET} = 50\text{pF}$ , unless otherwise noted.

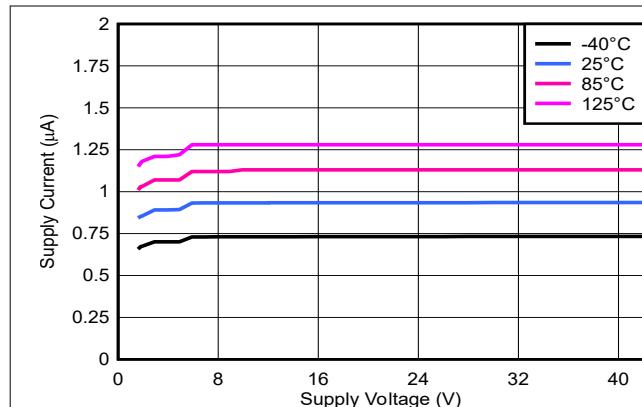


Figure 6-3. Supply Current vs Supply Voltage

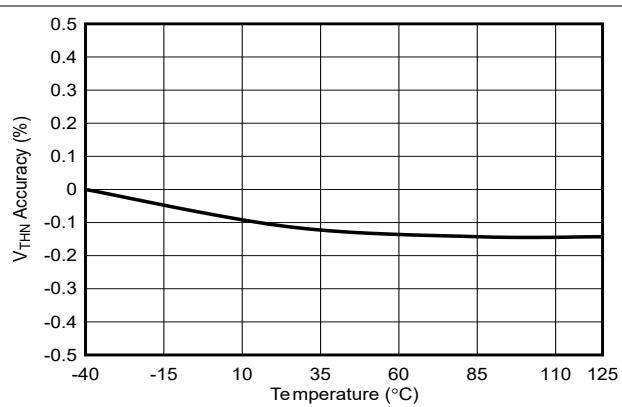


Figure 6-4.  $V_{THN}$  Accuracy vs Temperature

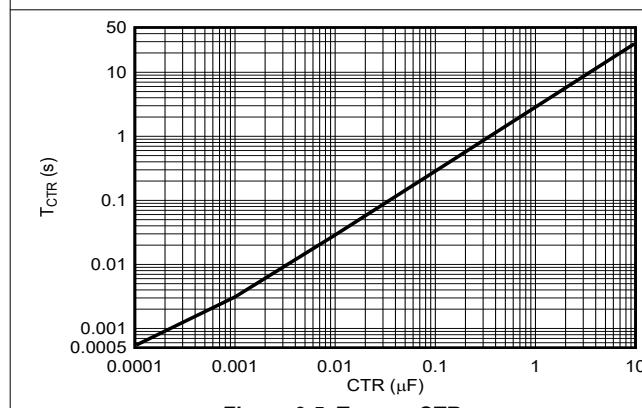


Figure 6-5.  $T_{CTR}$  vs  $CTR$

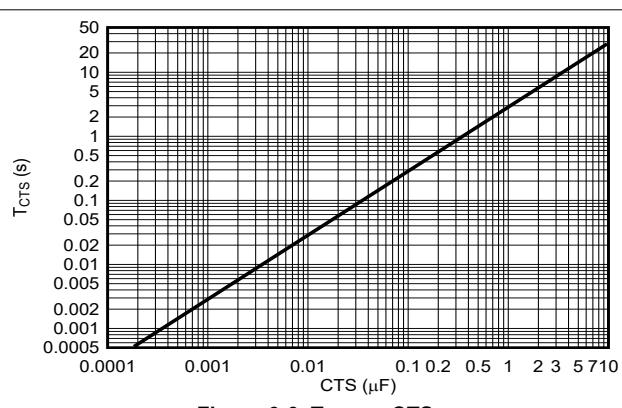


Figure 6-6.  $T_{CTS}$  vs  $CTS$

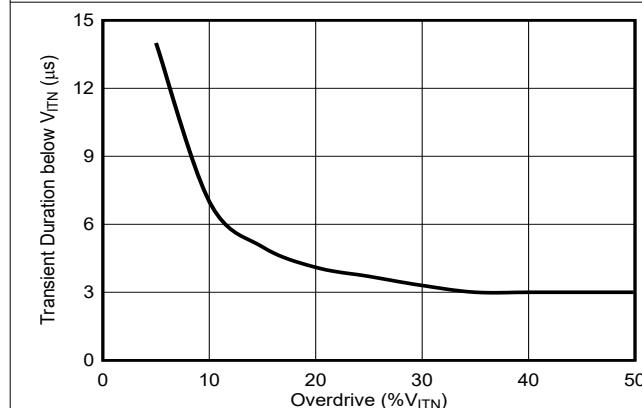


Figure 6-7. Transient Duration at Sense vs Sense Threshold Overdrive Voltage (CTS = Open)

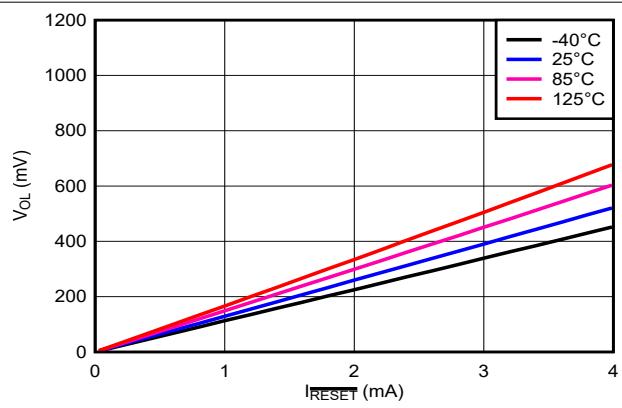


Figure 6-8. RESET Current (Sink) vs  $V_{OL}$  ( $V_{DD} = 3.3\text{V}$ )

## 6.9 Typical Characteristics (continued)

At  $T_A = 25^\circ\text{C}$ ,  $V_{DD} = 3.3\text{V}$ ,  $R_{RESET} = 100\text{k}\Omega$ , and  $C_{LRESET} = 50\text{pF}$ , unless otherwise noted.

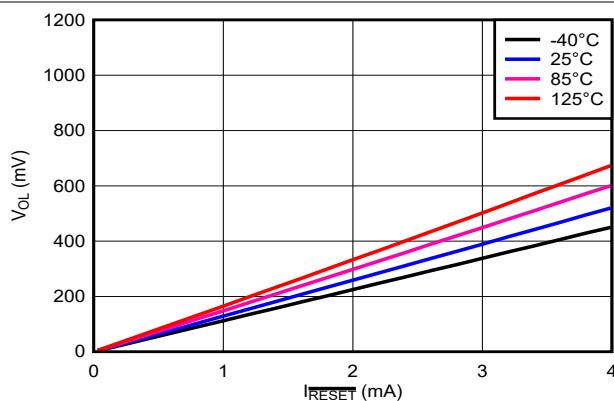


Figure 6-9. RESET Current (Sink) vs  $V_{OL}$  ( $V_{DD} = 12\text{V}$ )

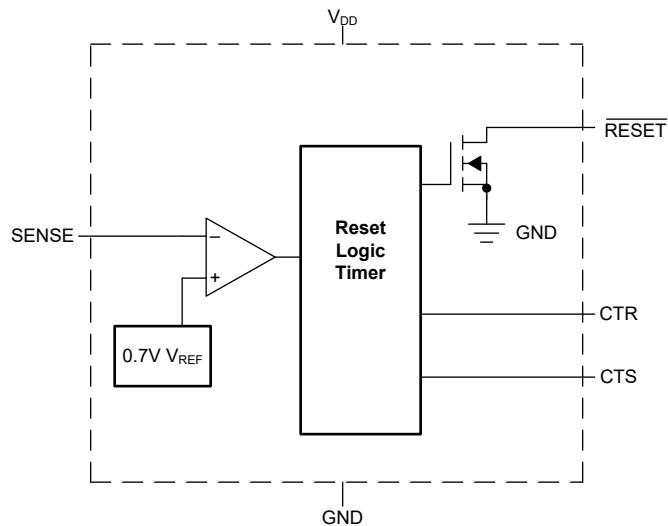
## 7 Detailed Description

### 7.1 Overview

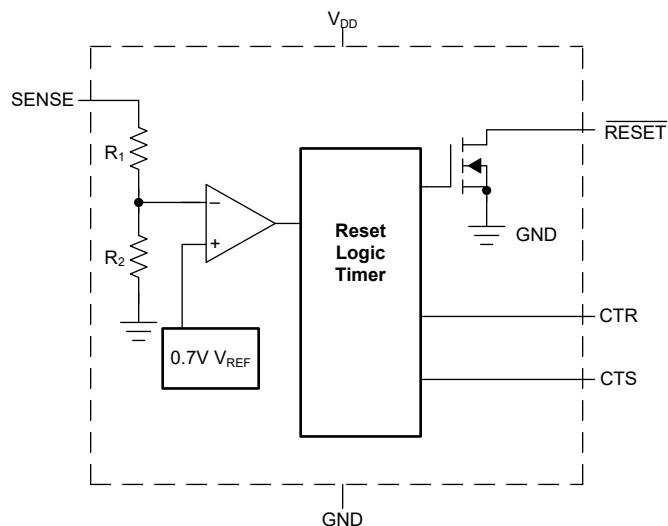
The TPS3842-Q1 high voltage supervisor product family is designed to assert a **RESET/RESET** signal when the **SENSE** pin voltage crosses  $V_{IT}$  and stays beyond  $V_{IT}$  for user defined time. The **RESET/RESET** output remains asserted for a user-adjustable time until after **SENSE** voltages returns above the respective threshold and hysteresis.

**VDD**, **SENSE** and **RESET/RESET** pins can support 42V continuous operation. **VDD**, **SENSE**, and **RESET/RESET** voltage levels can be independent of each other. The TPS3842-Q1 features capacitor programmable sense time delay (CTS) to set a minimum duration of a undervoltage event before **RESET/RESET** is asserted. CTS feature also functions as a programmable de-glitch to avoid false resets. The TPS3842-Q1 also features a capacitor programmable reset time delay (CTR) to set a minimum duration of **RESET/RESET** assertion after a undervoltage event recovers.

### 7.2 Functional Block Diagram



**Figure 7-1. Undervoltage Adjustable-Voltage Version**



**Figure 7-2. Undervoltage Fixed-Voltage Version**

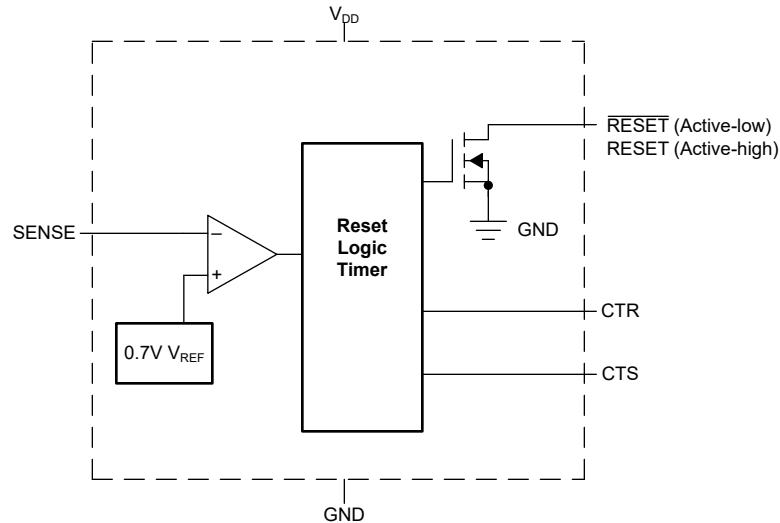


Figure 7-3. Overvoltage Adjustable-Voltage Diagram

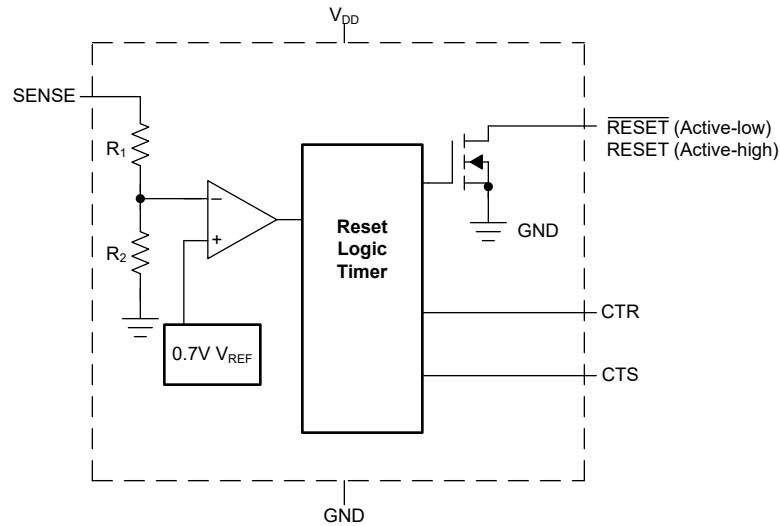


Figure 7-4. Overvoltage Fixed-Voltage Diagram

## 7.3 Feature Description

A broad range of voltage threshold and hysteresis options are available for the TPS3842, allowing this device to be used in a wide array of applications. Reset threshold voltages can be factory-set from adjustable 0.7V or fixed from 2.7V to 18V. The adjustable variant can be set to any voltage above 0.7V using an external resistor divider. Connecting a capacitor between CTR and GND allows the designer to select any reset delay period up to 10 $\mu$ F. Connecting a capacitor between CTS and GND allows the designer to select any sense delay period up to 10 $\mu$ F.

### 7.3.1 SENSE Input

The SENSE input provides a pin at which any system voltage can be monitored. If the voltage on this pin drops below  $V_{ITN}$  for a  $t_{PD}+t_{CTS}$  time interval, then  $\overline{\text{RESET}}/\text{RESET}$  is asserted. The comparator has a built-in hysteresis to suppress unintended  $\overline{\text{RESET}}/\text{RESET}$  assertions and de-assertions. For noisy environments, good analog design practice is to put a 1nF bypass capacitor on the SENSE input to reduce sensitivity to transients and layout parasitics or leverage the CTS feature to set a minimum fault time interval before  $\overline{\text{RESET}}/\text{RESET}$  is asserted.

Figure 7-5 illustrates an example of how to adjust the voltage threshold with external resistor dividers. The resistors can be calculated depending on the desired voltage threshold and device part number. TI recommends using the 700mV threshold option when using an external resistor divider. The variant bypasses the internal resistor ladder for higher accuracy when using external resistors.

For example, consider a 12V rail,  $V_{MON}$ , being monitored for undervoltage (UV) using of the TPS3842A011DRLRQ1 variant, as shown in Figure 7-5. The monitored UV threshold, denoted as  $V_{MON-}$ , is the desired voltage where the device asserts the reset. For this example  $V_{MON-} = 5.8V$ . To assert an undervoltage reset the voltage at the sense pin,  $V_{SENSE}$ , needs to be equal to the input threshold negative,  $V_{ITN}$ . For this example variant  $V_{SENSE} = V_{ITN} = 0.7V$ . Using  $R_1$  and  $R_2$  the correlation between  $V_{MON-}$  and  $V_{SENSE}$  can be seen in Equation 1. Assuming  $R_1 = 100\text{k}\Omega$ , and  $R_2$  can be calculated as  $R_2 = 13.7\text{k}\Omega$ .

$$V_{SENSE} = V_{MON-} \times (R_2 \div (R_1 + R_2)) \quad (1)$$

The TPS3842-Q1 hysteresis depends on the configuration selected. For the reset signal to become deasserted,  $V_{MON}$  must go above  $V_{ITN} + V_{HYS}$ . For this example variant a 1% voltage threshold hysteresis was selected. Therefore,  $V_{MON}$  equals 5.858V when the reset signal becomes deasserted. If a 10% hysteresis option was instead used,  $V_{MON}$  equals 6.38V when the reset signal becomes deasserted.

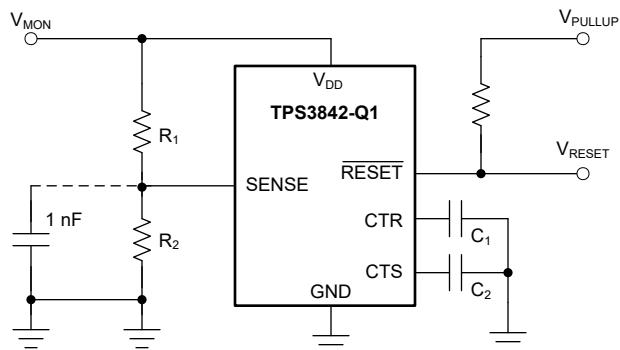


Figure 7-5. Using the TPS3842A011DRLRQ1 to Monitor a User-Defined Threshold Voltage

### 7.3.1.1 SENSE Hysteresis

TPS3842-Q1 device offers built-in hysteresis around the UV threshold to avoid erroneous RESET/RESET. The hysteresis ( $V_{HYS}$ ) is added to the negative thresholds ( $V_{ITN}$ ) and subtracted for positive thresholds ( $V_{ITP}$ ).

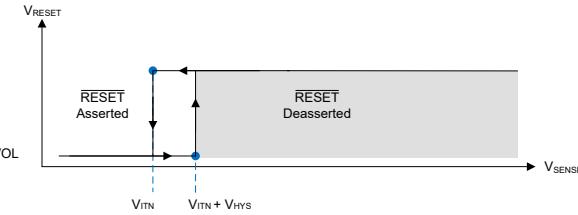


Figure 7-6. Hysteresis (Undervoltage Active-Low)

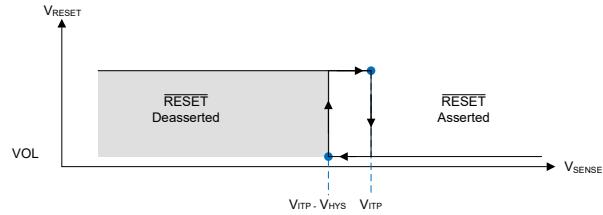


Figure 7-7. Hysteresis (Overvoltage Active-Low)

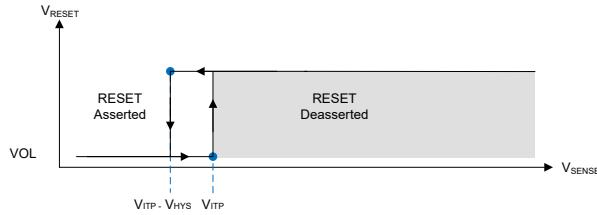


Figure 7-8. Hysteresis (Overvoltage Active-High)

Table 7-1. Common Adjustable Hysteresis Lookup Table

Part Number	DEVICE HYSTERESIS OPTION
TPS3842Axx1DRLRQ1	1%
TPS3842Axx5DRLRQ1	5%
TPS3842Axx0DRLRQ1	10%

Hysteresis is dependent on the device  $V_{IT}$  including  $V_{IT}$  accuracy and deviations.

Undervoltage (UV)

$$V_{ITN} = 700\text{mV}$$

$$\text{Voltage Hysteresis } (V_{HYS}) = 1\% = V_{ITN} \times 1\% = 7\text{mV}$$

$$\text{Release Voltage} = V_{ITN} + V_{HYS} = 707\text{mV}$$

Overvoltage (OV)

$$V_{ITP} = 700\text{mV}$$

$$\text{Voltage Hysteresis } (V_{HYS}) = 1\% = V_{ITP} \times 1\% = 7\text{mV}$$

$$\text{Release Voltage} = V_{ITP} - V_{HYS} = 693\text{mV}$$

### 7.3.2 Selecting the SENSE Delay Time

TPS3842-Q1 has adjustable sense time delay with external capacitors.

- A capacitor on CTS programs the minimum fault time interval before RESET is asserted.
- No capacitor on this pin gives the fastest sense delay time indicated by  $t_{PD}$  in [Section 6.6](#).
- Parasitic capacitance on the CTS pin counts as CTS capacitance and increases  $t_{CTS}$ .

The time delay ( $t_{CTS}$ ) can be programmed by connecting a capacitor between CTS pin and GND.

The relationship between external capacitor  $C_{CTS\_EXT\ (typ)}$  and the time delay  $t_{CTS\ (typ)}$  is given by [Equation 2](#).

$$t_{CTS\ (typ)} = 2.858 \times C_{CTS\_EXT\ (typ)} \quad (2)$$

$t_{CTS\ (typ)}$  = is given in seconds (s)

$C_{CTS\_EXT\ (typ)}$  = is given in microfarads ( $\mu F$ )

The sense delay varies according to the external capacitor ( $C_{CTS\_EXT}$ ). The minimum and maximum variance due to the constant is show in [Equation 3](#) and [Equation 4](#):

$$t_{CTS\ (max)} = 3.715 \times C_{CTS\_EXT\ (max)} \quad (3)$$

$$t_{CTS\ (min)} = 2 \times C_{CTS\_EXT\ (min)} \quad (4)$$

Make sure there is enough time for the capacitor to fully discharge when a voltage fault occurs to prevent the CTS capacitor from having charge before the next fault. Also, having a too large of a capacitor value can cause very slow charge up (rise times) and system noise can cause the internal circuit to trip earlier or later near the threshold.

---

#### Note

Leakages on the capacitor can effect accuracy of sense time delay.

---

### 7.3.3 Selecting the RESET Delay Time

TPS3842-Q1 has adjustable reset release time delay with external capacitors.

- A capacitor on CTR programs the reset time delay of the output.
- No capacitor on this pin gives the fastest reset delay time.
- Parasitic capacitance on the CTR pin counts as CTR capacitance and increases  $t_{CTR}$ .

The time delay ( $t_{CTR}$ ) can be programmed by connecting a capacitor between CTR pin and GND.

The relationship between external capacitor  $C_{CTR\_EXT}$  (typ) and the time delay  $t_{CTR}$  (typ) is given by [Equation 5](#).

$$t_{CTR} \text{ (typ)} = 2.858 \times C_{CTR\_EXT} \text{ (typ)} \quad (5)$$

$t_{CTR}$  (typ) = is given in seconds (s)

$C_{CTR\_EXT}$  (typ) = is given in microfarads ( $\mu$ F)

The reset delay varies according to the external capacitor ( $C_{CTR\_EXT}$ ). The minimum and maximum variance due to the constant is show in [Equation 6](#) and [Equation 7](#):

$$t_{CTR} \text{ (max)} = 3.715 \times C_{CTR\_EXT} \text{ (max)} \quad (6)$$

$$t_{CTR} \text{ (min)} = 2 \times C_{CTR\_EXT} \text{ (min)} \quad (7)$$

Having a too large of a capacitor value ( $>10\mu$ F) can cause very slow charge up (rise times) due to capacitor leakage and system noise can cause the internal circuit to hold  $\overline{\text{RESET}}$  active.

\* Leaks on the capacitor can effect accuracy of reset time delay.

### 7.3.4 RESET Output

$\overline{\text{RESET}}$  (active low) denoted with a bar above the pin label.  $\overline{\text{RESET}}$  remains high voltage ( $V_{OH}$ , deasserted) (open-drain variant  $V_{OH}$  is measured against the pullup voltage) as long as sense voltage is in normal operation above the threshold boundary and VDD voltage is above VDD(min). If SENSE falls below  $V_{ITN}$  for a time period longer than  $t_{CTS}$ ,  $\overline{\text{RESET}}$  is asserted, driving the  $\overline{\text{RESET}}$  pin to a low impedance.

Once SENSE is above  $V_{ITN} + V_{HYS}$ , a delay circuit (CTR) is enabled that holds  $\overline{\text{RESET}}$  low for a specified reset delay period. Once the reset delay has expired, the  $\overline{\text{RESET}}$  pin goes to a high impedance state.

For overvoltage active low variants,  $\overline{\text{RESET}}$  asserts when SENSE goes above  $V_{ITP}$  for a time period longer than  $t_{CTS}$ . Once SENSE is below  $V_{ITP} - V_{HYS}$ , a delay circuit (CTR) is enabled that holds  $\overline{\text{RESET}}$  low for a specified reset delay period. Once the reset delay has expired, the  $\overline{\text{RESET}}$  pin goes to a high impedance state.

For overvoltage active high variants, RESET deasserts when SENSE goes above  $V_{ITP}$  for a time period longer than  $t_{CTS}$ . Once SENSE is below  $V_{ITP} - V_{HYS}$ , a delay circuit (CTR) is enabled that keeps RESET deasserted for a specified reset delay period. Once the reset delay has expired, the RESET pin asserts.

Open-drain output requires an external pull-up resistor to hold the voltage high to the required voltage logic. Connect the pull-up resistor to the proper voltage rail to enable the output to be connected to other devices at the correct interface voltage levels. RESET/RESET supports pull-up voltages up to 42V and is independent of VDD and SENSE voltages.

To select the right pull-up resistor, consider system  $V_{OH}$  and the Open-Drain Leakage Current ( $I_{LKG}$ ) provided in the electrical characteristics to set the maximum pull-up resistor value. Low pull-up resistor values increase the amount of current through the internal open-drain output. The current through the open-drain output must be lower than the  $I_{RESET}$  of the device.

## 7.4 Device Functional Modes

**Table 7-2. Undervoltage Truth Table**

SENSE > $V_{ITN}$	RESET	VDD
0	L	$VDD > VDD(\min)$
1	H	$VDD > VDD(\min)$
0 or 1	L	$VDD(\min) > VDD > V_{POR}$

**Table 7-3. Overvoltage Truth Table**

SENSE < $V_{ITP}$	RESET	RESET	VDD
0	L	H	$VDD > VDD(\min)$
1	H	L	$VDD > VDD(\min)$
0 or 1	L	H	$VDD(\min) > VDD > V_{POR}$

### 7.4.1 Normal Operation ( $V_{DD} > V_{DD(\min)}$ )

When  $V_{DD}$  is greater than  $V_{DD(\min)}$ , the  $\overline{\text{RESET}}$ /RESET signal is determined by the voltage on the SENSE pin.

- The  $\overline{\text{RESET}}$ /RESET signal corresponds to the voltage on SENSE relative to  $V_{ITN}$  or  $V_{ITP}$ .

### 7.4.2 Above Power-On Reset but Less Than $V_{DD(\min)}$ ( $V_{POR} < V_{DD} < V_{DD(\min)}$ )

When the voltage on  $V_{DD}$  is less than the device  $V_{DD(\min)}$  voltage, and greater than the power-on reset voltage ( $V_{POR}$ ), the  $\overline{\text{RESET}}$  signal is asserted and low impedance regardless of the voltage on the SENSE pin. RESET (active high) signal is deasserted regardless of the voltage on the SENSE pin.

### 7.4.3 Below Power-On Reset ( $V_{DD} < V_{POR}$ )

When the voltage on  $V_{DD}$  is lower than the required voltage ( $V_{POR}$ )  $\overline{\text{RESET}}$ /RESET is undefined.

## 8 Application and Implementation

### Note

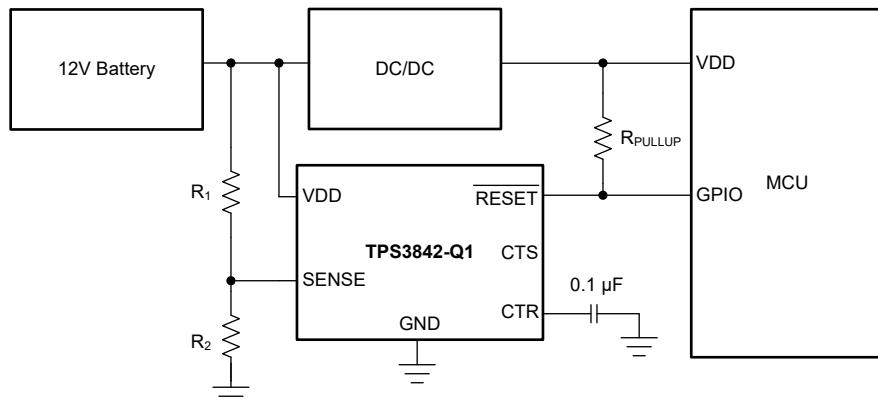
Information in the following applications sections is not part of the TI component specification, and TI does not warrant its accuracy or completeness. TI's customers are responsible for determining suitability of components for their purposes, as well as validating and testing their design implementation to confirm system functionality.

### 8.1 Application Information

The following sections describe in detail proper device implementation, depending on the final application requirements.

### 8.2 Typical Application

A typical application of the TPS3842-Q1 used to monitor a 12V automotive battery is shown in [Figure 8-1](#). The open-drain **RESET** output is typically connected to the **RESET** input of a microprocessor to signal when the Battery is below  $V_{ITN}$ . A pullup resistor must be used to hold this line high when **RESET** is not asserted. The **RESET** output is undefined for voltage below  $V_{POR}$ , but this characteristic is normally not a problem because most microprocessors do not function below this voltage.



**Figure 8-1. Typical Application of the TPS3842-Q1 Monitoring a 12V Power Supply**

#### 8.2.1 Design Requirements

**Table 8-1. Design Parameters**

PARAMETER	DESIGN REQUIREMENT
Voltage Threshold	Typical UV voltage threshold 5.5V
Output logic	Open-Drain
SENSE delay	< 0.2ms
RESET delay	300ms

### 8.2.2 Detailed Design Procedure

The TPS3842-Q1 uses high-voltage SENSE and  $V_{DD}$  inputs to monitor a 12V battery for undervoltage. In this design example TPS3842A011DRLRQ1 is used.

The negative-going threshold voltage,  $V_{ITN}$ , is set by the device variant. In this example, the nominal supply voltage from the battery is 12V. Setting a undervoltage threshold of 5.5V (6.5V under 12V) makes sure that the device resets before supply voltage violates the allowed boundary for the DC/DC and indicates the battery is discharged. The adjustable voltage variant is chosen and  $R_1$  and  $R_2$  are adjusted to meet the threshold. Assuming  $R_2$  equal to 10k $\Omega$  and  $R_1$  is calculated as 68.5k $\Omega$ . For additional information on selecting resistor values see [Section 7.3.1](#). TPS3842-Q1 also supports fixed voltage threshold variants. Threshold voltage decoding can be found in [Section 4](#).

#### 8.2.2.1 Meeting the Sense and Reset Delay

The TPS3842-Q1 features both reset assertion (sense) delay,  $t_{CTS}$ , and reset deassertion (reset) delay,  $t_{CTR}$ . [Section 7.3.2](#) and [Section 7.3.3](#) show how to set the timings for the capacitor-programmable delays. The application requires less than 0.2ms sense delay, thus no capacitor is used and CTS is left open. The application requires greater than 300ms reset delay, thus a 0.1 $\mu$ F capacitor is used.

#### 8.2.3 Application Curve

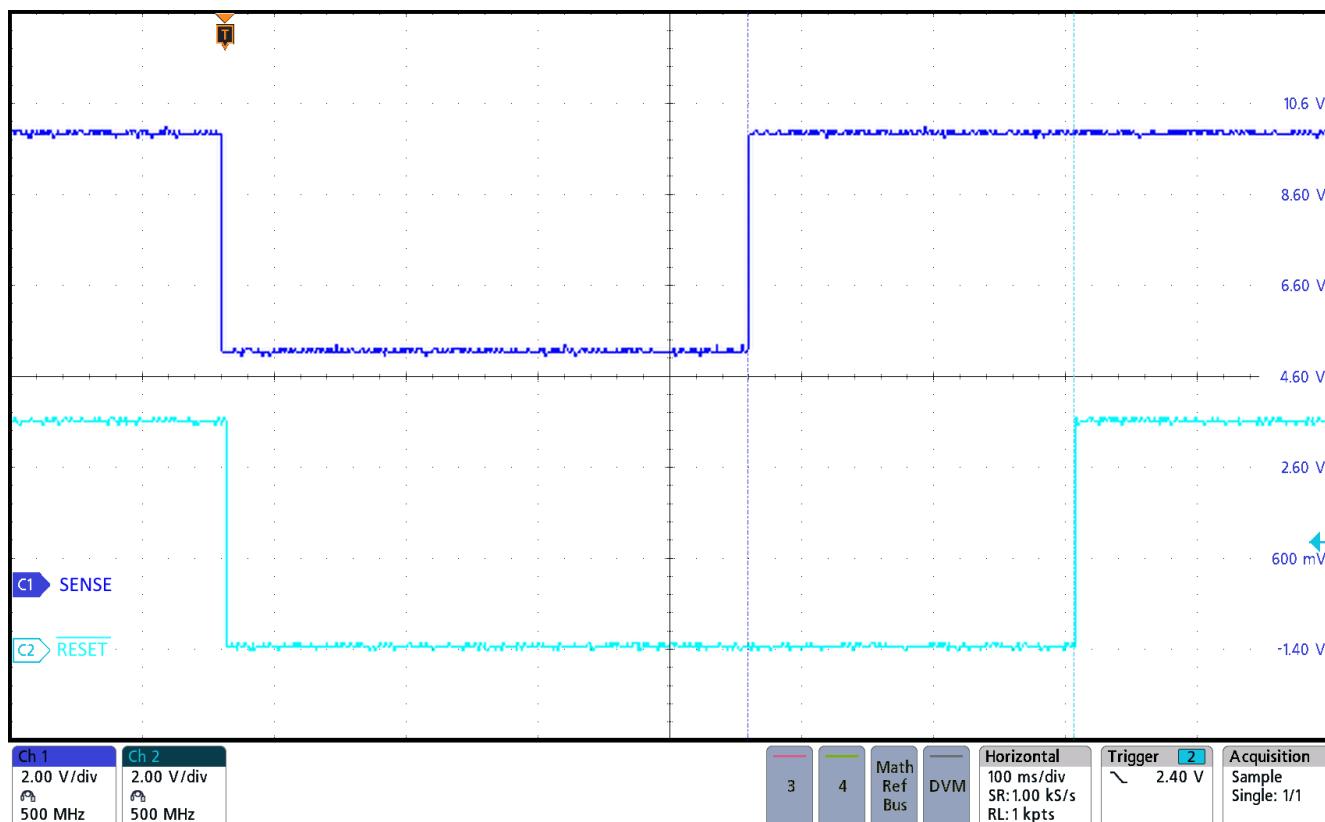


Figure 8-2. TPS3842-Q1 Detecting Undervoltage Fault and **RESET** Recovery

## 8.3 Power Supply Recommendations

TPS3842-Q1 is designed to operate from an input supply with a  $V_{DD}$  voltage between 1.9V (minimum operation) to 42V (maximum operation). Good analog design practice recommends placing a minimum 0.1 $\mu$ F ceramic capacitor as near as possible to the  $V_{DD}$  pin.

## 8.4 Layout

### 8.4.1 Layout Guidelines

- Make sure that the connection to the  $V_{DD}$  pin is low impedance. Good analog design practice is to place a greater than 0.1 $\mu$ F ceramic capacitor as near as possible to the  $V_{DD}$  pin.
- For noisy environments and to improve noise immunity on the SENSE pins, an optional 1nF capacitor between the SENSE pin and GND can reduce the sensitivity to transient voltages on the monitored signal. An alternative to improve noise immunity is to use the CTS feature.
- If a capacitor is used on CTS or CTR, place these components as close as possible to the respective pins. If the capacitor adjustable pins are left unconnected, make sure to minimize the amount of parasitic capacitance to not affect the  $t_{PD}$  or  $t_{CTR}$ .
- Place the pull-up resistors on  $\overline{RESET}/RESET$  as close to the pin as possible.
- When laying out metal traces, separate high voltage traces from low voltage traces as much as possible.
- Do not have high voltage metal pads or traces closer than 20mils (0.5mm) to the low voltage metal pads or traces.

### 8.4.2 Layout Example

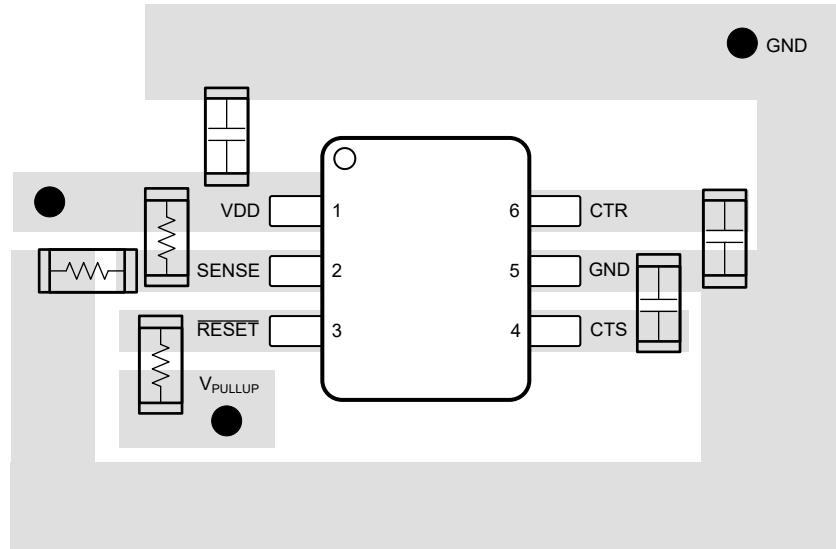


Figure 8-3. TPS3842-Q1 Recommended Layout

## 9 Device and Documentation Support

### 9.1 Device Support

### 9.2 Documentation Support

### 9.3 Support Resources

TI E2E™ support forums are an engineer's go-to source for fast, verified answers and design help — straight from the experts. Search existing answers or ask your own question to get the quick design help you need.

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### 9.4 Trademarks

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### 9.5 Electrostatic Discharge Caution



This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

### 9.6 Glossary

[TI Glossary](#) This glossary lists and explains terms, acronyms, and definitions.

## 10 Revision History

NOTE: Page numbers for previous revisions may differ from page numbers in the current version.

<b>Changes from Revision A (August 2024) to Revision B ( October 2025)</b>	<b>Page</b>
• Updated <i>Title</i> to include Overvoltage.....	1
• Added overvoltage option throughout the document.....	1
• Updated <i>Features</i> list.....	1
• Added overvoltage to the <i>Description</i> .....	1
• Removed nomenclature table.....	3
• Updated device naming convention table.....	3
• Updated the <i>Pin Configuration and Functions</i> .....	4
• Updated <i>Recommended Operating Conditions, Electrical Characteristics, Timing Requirements, Switching Characteristics</i> to include Overvoltage variant electrical specifications.....	5
• Added overvoltage to the <i>Timing Diagram</i> .....	8
• Added overvoltage description to the <i>Overview</i> .....	11
• Updated the <i>Functional Block Diagram</i> .....	11
• Updated 9.5V to 18V in the <i>Feature Description</i> .....	13
• Added overvoltage RESET to the <i>SENSE Input</i> description.....	13
• Added overvoltage hysteresis diagrams and equations to <i>SENSE Hysteresis</i> .....	14
• Added RESET functionality to the <i>RESET Output</i> .....	16
• Added overvoltage truth table to the <i>Device Functional Modes</i> .....	17
• Added RESET description to the <i>Device Functional Modes</i> .....	17
• Added RESET to the <i>Layout Guidelines</i> description.....	20

Changes from Revision * (April 2024) to Revision A (August 2024)	Page
• Production Data Release.....	1

## 11 Mechanical, Packaging, and Orderable Information

The following pages include mechanical, packaging, and orderable information. This information is the most-current data available for the designated devices. This data is subject to change without notice and without revision of this document. For browser-based versions of this data sheet, see the left-hand navigation pane.

**PACKAGING INFORMATION**

Orderable part number	Status (1)	Material type (2)	Package   Pins	Package qty   Carrier	RoHS (3)	Lead finish/ Ball material (4)	MSL rating/ Peak reflow (5)	Op temp (°C)	Part marking (6)
PPS3842C011DRLRQ1	Active	Preproduction	SOT-5X3 (DRL)   6	4000   LARGE T&R	-	Call TI	Call TI	-40 to 125	
TPS3842A010DRLRQ1	Active	Production	SOT-5X3 (DRL)   6	4000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-	A010Q
TPS3842A010DRLRQ1.A	Active	Production	SOT-5X3 (DRL)   6	4000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	A010Q
TPS3842A010DRLRQ1.B	Active	Production	SOT-5X3 (DRL)   6	4000   LARGE T&R	-	Call TI	Call TI	-40 to 125	
TPS3842A011DRLRQ1	Active	Production	SOT-5X3 (DRL)   6	4000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	A011Q
TPS3842A011DRLRQ1.A	Active	Production	SOT-5X3 (DRL)   6	4000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	A011Q
TPS3842A011DRLRQ1.B	Active	Production	SOT-5X3 (DRL)   6	4000   LARGE T&R	-	Call TI	Call TI	-40 to 125	
TPS3842A015DRLRQ1	Active	Production	SOT-5X3 (DRL)   6	4000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	A015Q
TPS3842A015DRLRQ1.A	Active	Production	SOT-5X3 (DRL)   6	4000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	A015Q
TPS3842A015DRLRQ1.B	Active	Production	SOT-5X3 (DRL)   6	4000   LARGE T&R	-	Call TI	Call TI	-40 to 125	
TPS3842A650DRLRQ1	Active	Production	SOT-5X3 (DRL)   6	4000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	A650Q
TPS3842A650DRLRQ1.A	Active	Production	SOT-5X3 (DRL)   6	4000   LARGE T&R	Yes	SN	Level-1-260C-UNLIM	-40 to 125	A650Q
TPS3842A650DRLRQ1.B	Active	Production	SOT-5X3 (DRL)   6	4000   LARGE T&R	-	Call TI	Call TI	-40 to 125	

<sup>(1)</sup> **Status:** For more details on status, see our [product life cycle](#).

<sup>(2)</sup> **Material type:** When designated, preproduction parts are prototypes/experimental devices, and are not yet approved or released for full production. Testing and final process, including without limitation quality assurance, reliability performance testing, and/or process qualification, may not yet be complete, and this item is subject to further changes or possible discontinuation. If available for ordering, purchases will be subject to an additional waiver at checkout, and are intended for early internal evaluation purposes only. These items are sold without warranties of any kind.

<sup>(3)</sup> **RoHS values:** Yes, No, RoHS Exempt. See the [TI RoHS Statement](#) for additional information and value definition.

<sup>(4)</sup> **Lead finish/Ball material:** Parts may have multiple material finish options. Finish options are separated by a vertical ruled line. Lead finish/Ball material values may wrap to two lines if the finish value exceeds the maximum column width.

<sup>(5)</sup> **MSL rating/Peak reflow:** The moisture sensitivity level ratings and peak solder (reflow) temperatures. In the event that a part has multiple moisture sensitivity ratings, only the lowest level per JEDEC standards is shown. Refer to the shipping label for the actual reflow temperature that will be used to mount the part to the printed circuit board.

<sup>(6)</sup> **Part marking:** There may be an additional marking, which relates to the logo, the lot trace code information, or the environmental category of the part.

---

Multiple part markings will be inside parentheses. Only one part marking contained in parentheses and separated by a "~" will appear on a part. If a line is indented then it is a continuation of the previous line and the two combined represent the entire part marking for that device.

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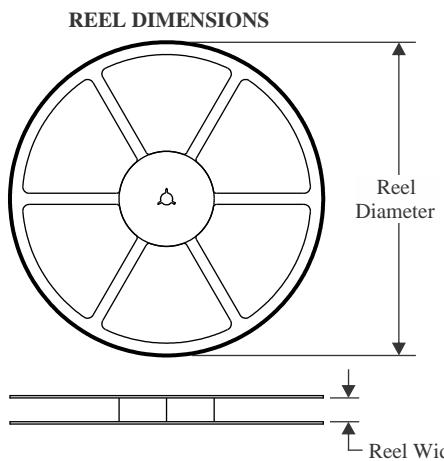
In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

**OTHER QUALIFIED VERSIONS OF TPS3842-Q1 :**

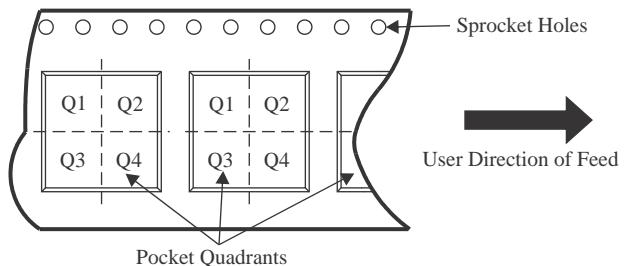
- Catalog : [TPS3842](#)

NOTE: Qualified Version Definitions:

- Catalog - TI's standard catalog product

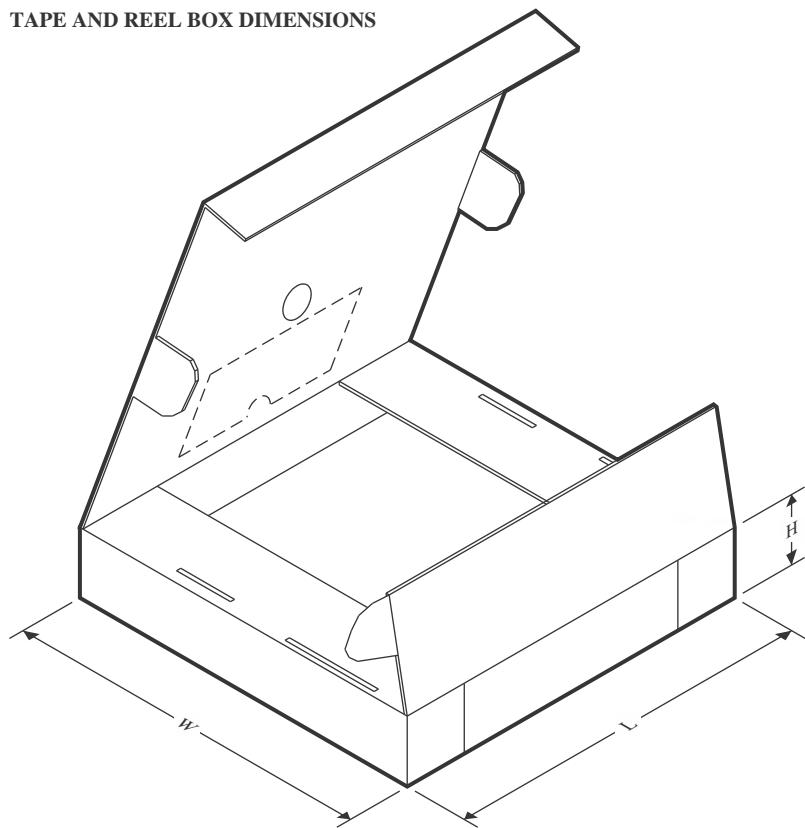
**TAPE AND REEL INFORMATION**


A0	Dimension designed to accommodate the component width
B0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

**QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE**


\*All dimensions are nominal

Device	Package Type	Package Drawing	Pins	SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TPS3842A010DRLRQ1	SOT-5X3	DRL	6	4000	180.0	8.4	2.0	1.8	0.75	4.0	8.0	Q3
TPS3842A011DRLRQ1	SOT-5X3	DRL	6	4000	180.0	8.4	2.0	1.8	0.75	4.0	8.0	Q3
TPS3842A015DRLRQ1	SOT-5X3	DRL	6	4000	180.0	8.4	2.0	1.8	0.75	4.0	8.0	Q3
TPS3842A650DRLRQ1	SOT-5X3	DRL	6	4000	180.0	8.4	2.0	1.8	0.75	4.0	8.0	Q3

**TAPE AND REEL BOX DIMENSIONS**


\*All dimensions are nominal

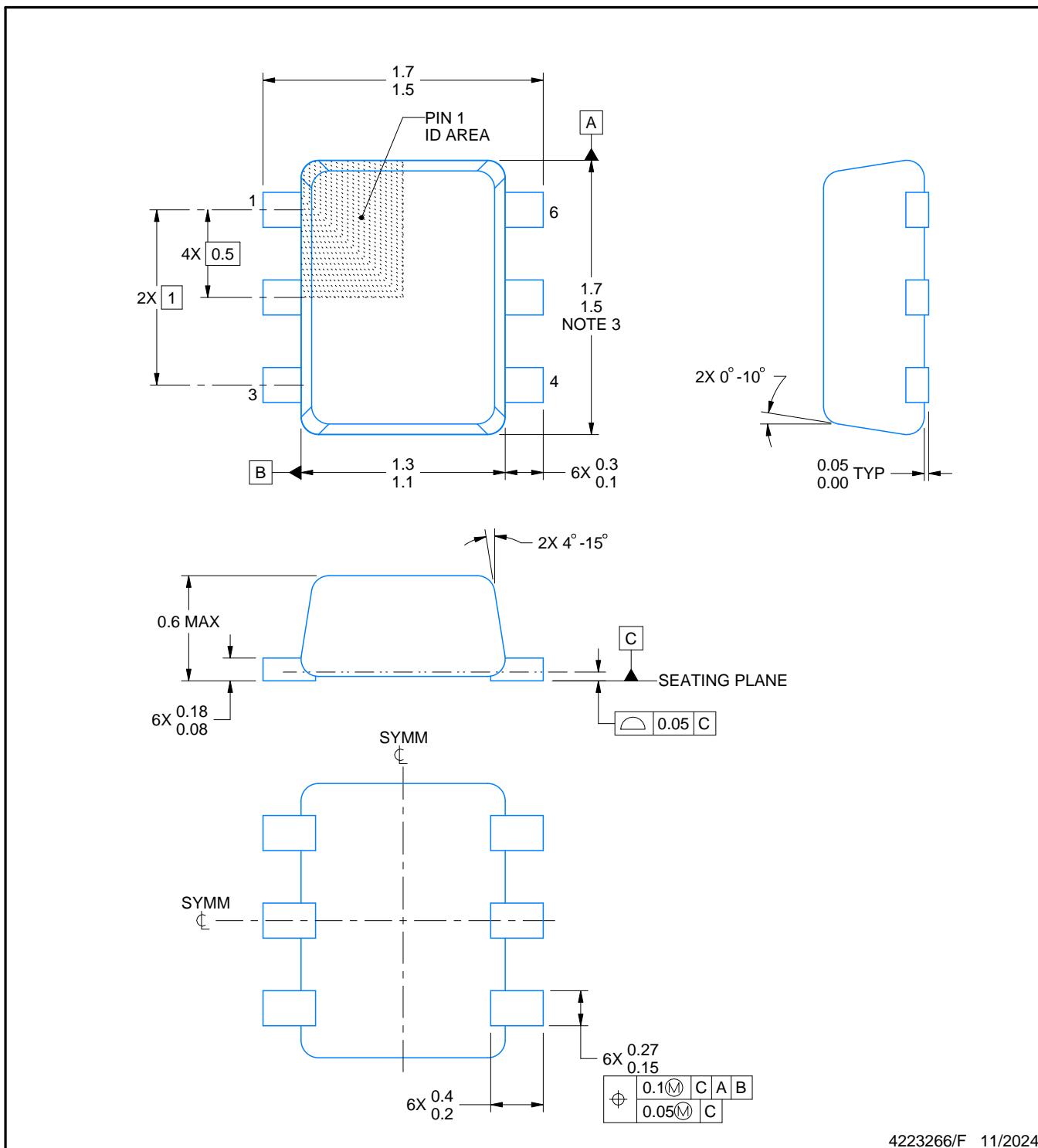
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TPS3842A010DRLRQ1	SOT-5X3	DRL	6	4000	210.0	185.0	35.0
TPS3842A011DRLRQ1	SOT-5X3	DRL	6	4000	210.0	185.0	35.0
TPS3842A015DRLRQ1	SOT-5X3	DRL	6	4000	210.0	185.0	35.0
TPS3842A650DRLRQ1	SOT-5X3	DRL	6	4000	210.0	185.0	35.0

# PACKAGE OUTLINE

## SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE

DRL0006A



4223266/F 11/2024

### NOTES:

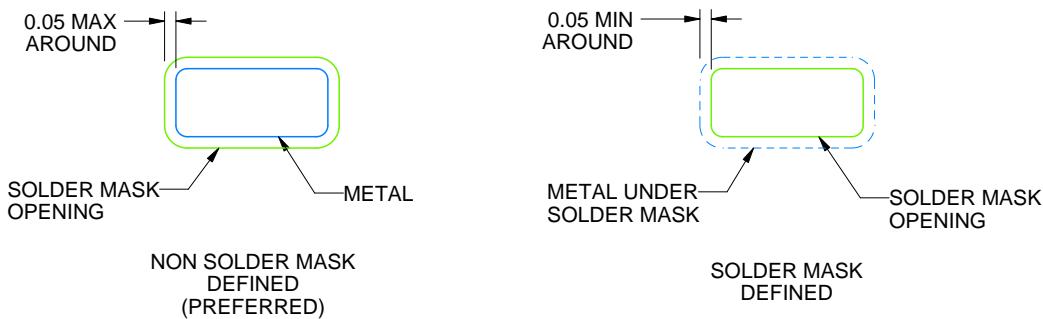
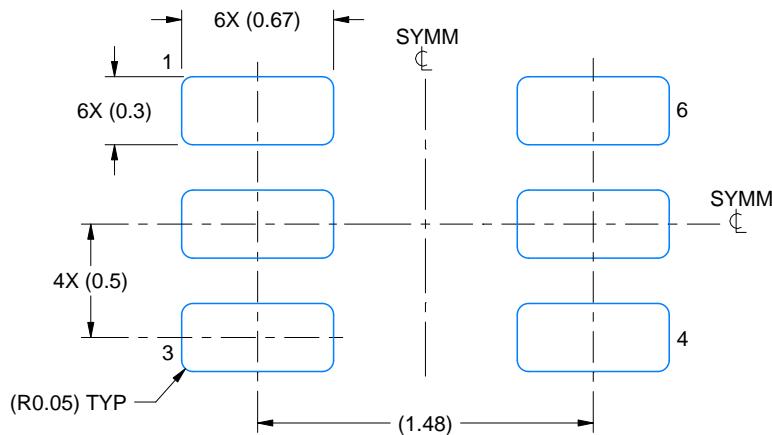
1. All linear dimensions are in millimeters. Any dimensions in parenthesis are for reference only. Dimensioning and tolerancing per ASME Y14.5M.
2. This drawing is subject to change without notice.
3. This dimension does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.15 mm per side.
4. Reference JEDEC registration MO-293 Variation UAAD

# EXAMPLE BOARD LAYOUT

DRL0006A

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



4223266/F 11/2024

NOTES: (continued)

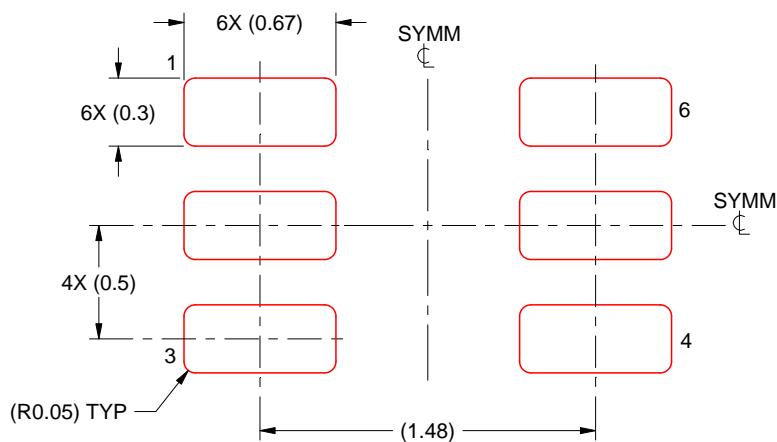
5. Publication IPC-7351 may have alternate designs.
6. Solder mask tolerances between and around signal pads can vary based on board fabrication site.
7. Land pattern design aligns to IPC-610, Bottom Termination Component (BTC) solder joint inspection criteria.

# EXAMPLE STENCIL DESIGN

DRL0006A

SOT - 0.6 mm max height

PLASTIC SMALL OUTLINE



SOLDER PASTE EXAMPLE  
BASED ON 0.1 mm THICK STENCIL  
SCALE:30X

4223266/F 11/2024

NOTES: (continued)

8. Laser cutting apertures with trapezoidal walls and rounded corners may offer better paste release. IPC-7525 may have alternate design recommendations.
9. Board assembly site may have different recommendations for stencil design.

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